FROM :LØRUSSO & LOUD

FAX NO. :703 739 9391

Mar. 26 2002 10:19AM P1

LORUSSO & LOUD

ATTORNEYS AT

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FACSIMILE COVER SHEET

DATE:

March 26, 2002

TO:

Ex. Moldonado

FROM:

Kathy Polucci

RE:

08/897,839

TOTAL NUMBER OF PAGES (INCLUDING COVER SHEET): 11

FACSIMILE NUMBER: 703 746-7316

MESSAGE

Further to our telephone discussion, I am herewith transmitting copies of the response and petition for extension of time as filed on November 19, 2001. A copy of the filing receipt is also transmitted herewith.

Please call if you need anything more.

Thanks.

Please telephone (703) 739-9393 if you do not receive or cannot clearly read the information transmitted herewith. This message is intended only for the use of the individual or entity to which it is addressed and may contain information that is privileged, confidential and exempt for disclosure under applicable law. If the reader of this message is not the intended recipient, or the employee or agent responsible for delivering this message to the intended recipient, you are hereby notified that any dissemination, distribution or copying of this communication is strictly prohibited. If you have received this communication in error, please notify us immediately by telephone and return the original message to us at the above address via the U.S. Postal Service. Thank you.

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The "Received" Stamp of the USPTO imprinted hereon acknowledges the filing of:

Description of Paper: Response to Office Action of June 19, 2001; Petition for Two Month Extension of Time; and Credit Card Payment Form for \$400.00

Name of Applicant/Patentee: NISHIMOTO et al

U.S.S.N. 08/897,839

FAX NO. :703 739 9391

Mar. 26 2002 10:20AM P3 Officed

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

NISHIMOTO et al

NISHIMOTO et al

Serial No.: 08/897,839

Filed: July 21, 1997

For: STRESS-ADJUSTED INSULATING
FILM FORMING METHOD,
SEMICONDUCTOR DEVICE AND
METHOD OF MANUFACTURING THE
SAME

SAME

RESPONSE TO OFFICE ACTION OF JUNE 19, 2001

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

Responsive to the office action of June 19, 2001, please amend the captioned application as follows:

IN THE CLAIMS:

Please cancel claims 48-52 and rewrite claims 43, 44 and 46 as follows:

43 (Amended) A stress-adjusted insulating film forming method for forming a multilayered

insulating film on a substrate, said method comprising:

(a) forming a first insulating layer with a first type of stress;